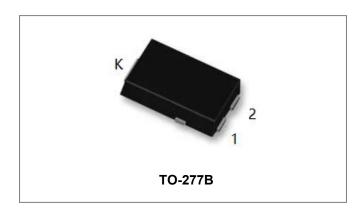




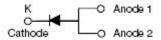
ST15100S SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- "-A" is an AEC-Q101 qualified device
- Terminals finish: Tin Lead-free plated
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, at 25 °C unless otherwise specified):

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	T _C =123°C, In DC	15	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	220	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 15A, Pulse, T _J = 25 °C	0.68	0.71	V
	V_{F2}	@ 15A, Pulse, T _J = 125 °C	0.60	0.64	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.01	0.5	mA
Reverse Current*	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	7.5	50	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	650	-	pF

^{*} Pulse width < 300 µs, duty cycle < 2%





Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

Ratings and Characteristics Curves

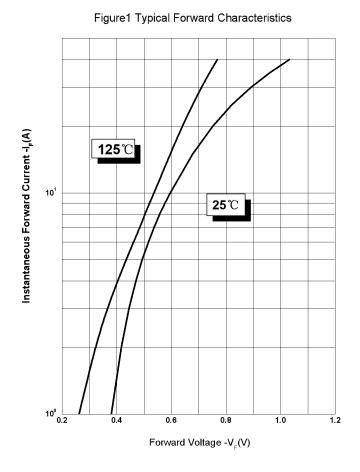
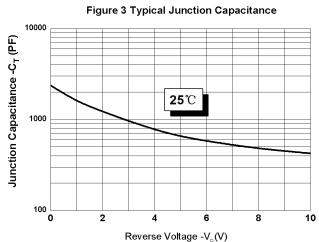


Figure 2 Typical Reverse Characteristics

10²
10¹
10¹
125 °C
10²
25 °C
Reverse Voltage -V_R(V)



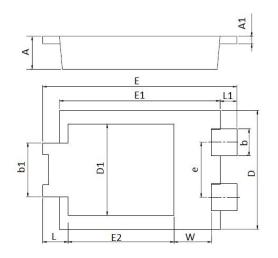
[•] China - Germany - Korea - Singapore - United States •

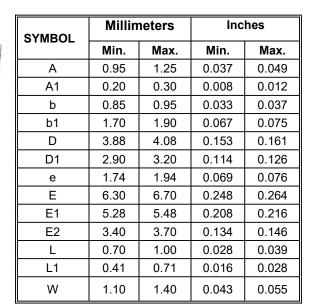
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •



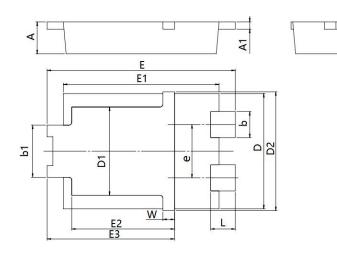


Mechanical Dimensions TO-277B





Mechanical Dimensions TO-277B(New)



SYMBOL	Millimeters		Inches		
STWIBOL	Min.	Max.	Min.	Max.	
Α	0.95	1.25	0.037	0.049	
A1	0.20	0.30	0.008	0.012	
b	0.85	0.95	0.033	0.037	
b1	1.70	1.90	0.067	0.075	
D	3.88	4.08	0.153	0.161	
D1	2.90	3.20	0.114	0.126	
D2	4.00	4.25	0.157	0.167	
е	1.74	1.94	0.069	0.076	
E	6.30	6.70	0.248	0.264	
E1	5.28	5.48	0.208	0.216	
E2	3.40	3.70	0.134	0.146	
E3	4.20	4.60	0.165	0.181	
L	0.65	1.05	0.025	0.041	
W	0.25	0.55	0.010	0.022	

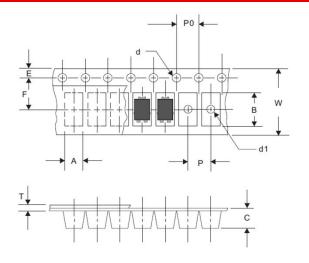
Notes: New Mechanical Dimensions is performed from date code 2236X.

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •





Carrier Tape Specification TO-277B



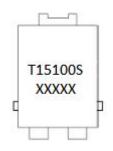
SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

Ordering Information

Device	Package	Shipping
ST15100S	TO-277B(Pb-Free)	5000pcs/ reel
ST15100STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

T = Device Type
15 = Forward Current (15A)
100 = Reverse Voltage (100V)
S = Package type
YY = Year

YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0





DISCLAIMER:

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